



### flowPIM 1

1200 V / 35 A

#### Topology features

- Kelvin Emitter for improved switching performance
- Open Emitter configuration
- Temperature sensor
- Converter+Brake+Inverter
- Tandem diode

#### Component features

- Easy paralleling
- Low turn-off losses
- Low collector emitter saturation voltage
- Positive temperature coefficient
- Short tail current
- Switching optimized for EMC

#### Housing features

- Base isolation:  $\text{Al}_2\text{O}_3$
- Convex shaped substrate for superior thermal contact
- Thermo-mechanical push-and-pull force relief
- Press-fit pin
- Reliable cold welding connection

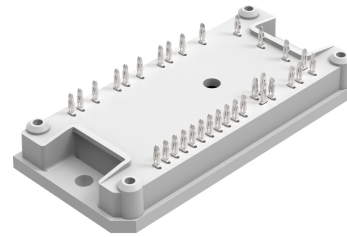
#### Target applications

- Embedded Drives
- Industrial Drives

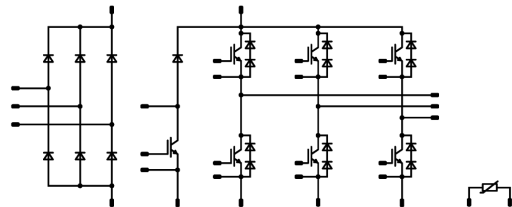
#### Types

- 10-PY12PMA035M703-P589A73Y

#### flow 1 12 mm housing



#### Schematic





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**10-PY12PMA035M703-P589A73Y**  
datasheet

## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
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### Inverter Switch

Collector-emitter voltage	$V_{CES}$		1200	V
Collector current (DC current)	$I_C$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	48	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	70	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	99	W
Gate-emitter voltage	$V_{GES}$		$\pm 20$	V
Short circuit ratings	$t_{SC}$	$V_{GE} = 15\text{ V}$ , $V_{CC} = 800\text{ V}$ $T_j = 150\text{ °C}$	9,5	$\mu s$
Maximum junction temperature	$T_{jmax}$		175	$^{\circ}\text{C}$

### Inverter Diode

Peak repetitive reverse voltage	$V_{RRM}$		1300	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	31	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	89	W
Maximum junction temperature	$T_{jmax}$		175	$^{\circ}\text{C}$

### Brake Switch

Collector-emitter voltage	$V_{CES}$		1200	V
Collector current (DC current)	$I_C$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	32	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	50	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	72	W
Gate-emitter voltage	$V_{GES}$		$\pm 20$	V
Short circuit ratings	$t_{SC}$	$V_{GE} = 15\text{ V}$ , $V_{CC} = 800\text{ V}$ $T_j = 150\text{ °C}$	9,5	$\mu s$
Maximum junction temperature	$T_{jmax}$		175	$^{\circ}\text{C}$



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datasheet

## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
<b>Brake Diode</b>				
Peak repetitive reverse voltage	$V_{RRM}$		1200	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	21	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	30	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	42	W
Maximum junction temperature	$T_{jmax}$		175	°C

## Rectifier Diode

Peak repetitive reverse voltage	$V_{RRM}$		1600	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	47	A
Surge (non-repetitive) forward current	$I_{FSM}$	Single Half Sine Wave, $t_p = 10\text{ ms}$ $T_j = 150\text{ °C}$	350	A
Surge current capability	$I^2t$		610	A <sup>2</sup> s
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	53	W
Maximum junction temperature	$T_{jmax}$		150	°C

## Module Properties

### Thermal Properties

Storage temperature	$T_{stg}$		-40...+125	°C
Operation temperature under switching condition	$T_{jop}$		-40...+( $T_{jmax} - 25$ )	°C

### Isolation Properties

Isolation voltage	$V_{isol}$	DC Test Voltage* $t_p = 2\text{ s}$	6000	V
Creepage distance			>12,7	mm
Clearance			7,91	mm
Comparative Tracking Index	CTI		≥ 200	

\*100 % tested in production



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Inverter Switch

#### Static

Gate-emitter threshold voltage	$V_{GE(th)}$			10	0,0035	25	5,4	6	6,6	V
Collector-emitter saturation voltage	$V_{CEsat}$		15		35	25 125 150		1,47 1,64 1,68	1,85 <sup>(1)</sup>	V
Collector-emitter cut-off current	$I_{CES}$		0	1200		25			80	μA
Gate-emitter leakage current	$I_{GES}$		20	0		25			200	nA
Internal gate resistance	$r_g$							None		Ω
Input capacitance	$C_{ies}$	0	10		25			7900		pF
Output capacitance	$C_{oes}$							270		pF
Reverse transfer capacitance	$C_{res}$							97		pF
Gate charge	$Q_g$	$V_{CC} = 600$ V	0/15		35	25		260		nC

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,96		K/W
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#### Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 4$ Ω $R_{goff} = 4$ Ω	±15	600	35	25 125 150		73,42 73,71 73,27		ns
Rise time	$t_r$					25 125 150		10,01 10,85 11,72		ns
Turn-off delay time	$t_{d(off)}$					25 125 150		151,83 172,63 181,28		ns
Fall time	$t_f$					25 125 150		97,02 120,23 126,56		ns
Turn-on energy (per pulse)	$E_{on}$					25 125 150		0,646 1,06 1,17		mWs
Turn-off energy (per pulse)	$E_{off}$					25 125 150		2,49 3,32 3,47		mWs



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datasheet

## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Inverter Diode

#### Static

Forward voltage	$V_F$				30	25 125 150		3,19 3,01 2,93	3,84 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_i = 1300$ V				25			1,6	µA

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						1,07		K/W
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#### Dynamic

Peak recovery current	$I_{RM}$	$di/dt=5362$ A/µs $di/dt=4088$ A/µs $di/dt=4424$ A/µs	$\pm 15$	600	35	25 125 150		53,4 57,55 58,7		A
Reverse recovery time	$t_{rr}$					25 125 150		19,21 134,98 149,98		ns
Recovered charge	$Q_r$					25 125 150		0,578 1,8 2,03		µC
Reverse recovered energy	$E_{rec}$					25 125 150		0,154 0,695 0,789		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		7177,28 4480,86 3819,39		A/µs



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Brake Switch

#### Static

Gate-emitter threshold voltage	$V_{GE(th)}$			10	0,0025	25	5,4	6	6,6	V
Collector-emitter saturation voltage	$V_{CEsat}$		15		25	25 125 150		1,64 1,89 1,95	2,1 <sup>(1)</sup>	V
Collector-emitter cut-off current	$I_{CES}$		0	1200		25			70	µA
Gate-emitter leakage current	$I_{GES}$		20	0		25			200	nA
Internal gate resistance	$r_g$							None		Ω
Input capacitance	$C_{ies}$	0	10	25				4800		pF
Output capacitance	$C_{oes}$							170		pF
Reverse transfer capacitance	$C_{res}$							57		pF
Gate charge	$Q_g$	$V_{CC} = 600$ V	0/15		25	25		180		nC

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						1,31		K/W
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#### Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 16$ Ω $R_{goff} = 16$ Ω	0/15	700	25	25 125 150		70,6 66,6 65		ns
Rise time	$t_r$					25 125 150		47,6 50,4 51,4		ns
Turn-off delay time	$t_{d(off)}$					25 125 150		262,2 290 296		ns
Fall time	$t_f$					25 125 150		101,1 117,29 119,12		ns
Turn-on energy (per pulse)	$E_{on}$					25 125 150		2,6 3,11 3,24		mWs
Turn-off energy (per pulse)	$E_{off}$					25 125 150		2,03 2,65 2,81		mWs



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Brake Diode

#### Static

Forward voltage	$V_F$				15	25 125 150		1,63 1,74 1,73	1,9 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_r = 1200$ V				25			30	µA

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						2,25		K/W
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#### Dynamic

Peak recovery current	$I_{RM}$	$di/dt=394$ A/µs $di/dt=319$ A/µs $di/dt=403$ A/µs	0/15	700	25	25 125 150		13,75 15,17 15,47		A
Reverse recovery time	$t_{rr}$					25 125 150		263,52 374,58 413,14		ns
Recovered charge	$Q_r$					25 125 150		1,92 2,9 3,15		µC
Reverse recovered energy	$E_{rec}$					25 125 150		0,778 1,28 1,41		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		111,02 85 72,04		A/µs



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## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Rectifier Diode

#### Static

Forward voltage	$V_F$				18	25 125 150		0,99 0,912 0,908	1,21 <sup>(1)</sup> 1,1 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_r = 1600$ V				25			50	μA

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						1,31		K/W
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### Thermistor

#### Static

Rated resistance	$R$					25		22		kΩ
Deviation of R100	$\Delta_{R/R}$	$R_{100} = 1484$ Ω				100	-5		5	%
Power dissipation	$P$					25		130		mW
Power dissipation constant	$d$					25		1,5		mW/K
B-value	$B_{(25/50)}$	Tol. $\pm 1$ %						3962		K
B-value	$B_{(25/100)}$	Tol. $\pm 1$ %						4000		K
Vincotech Thermistor Reference									I	

<sup>(1)</sup> Value at chip level

<sup>(2)</sup> Only valid with pre-applied Vincotech thermal interface material.



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# 10-PY12PMA035M703-P589A73Y

datasheet

## Inverter Switch Characteristics

figure 1. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

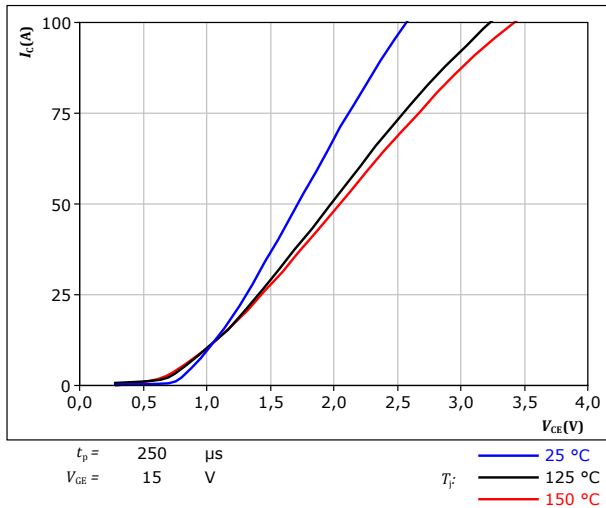


figure 2. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

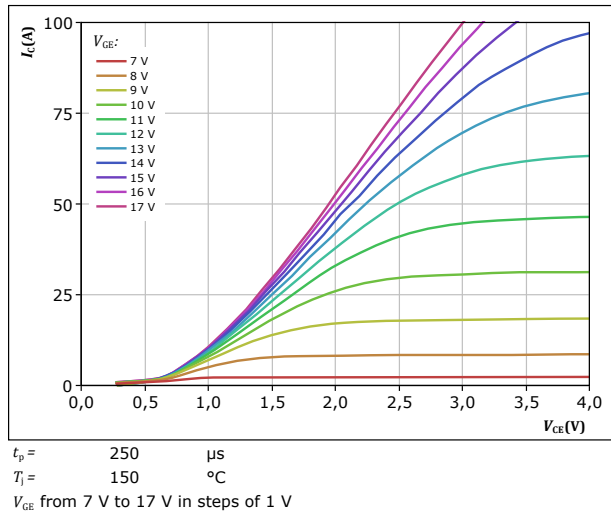


figure 3. IGBT

Typical transfer characteristics

$$I_C = f(V_{GE})$$

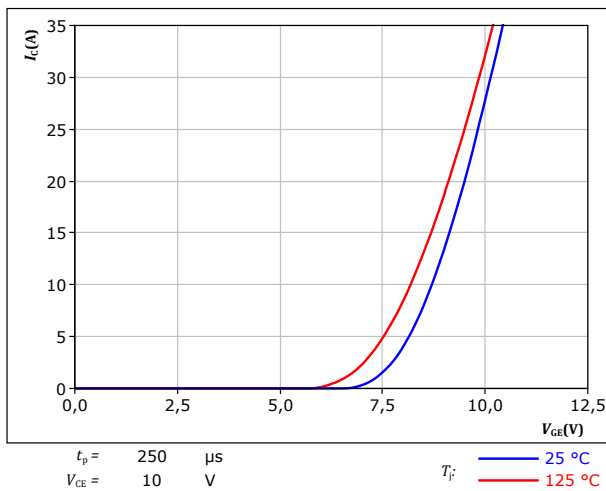
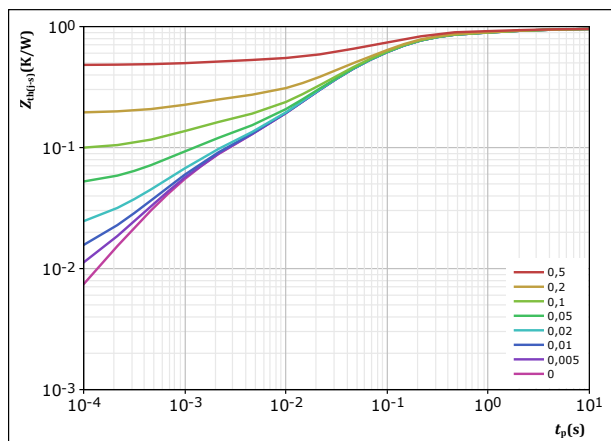


figure 4. IGBT

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



IGBT thermal model values	
$R$ (K/W)	$\tau$ (s)
3,36E-02	5,53E+00
1,00E-01	1,06E+00
5,28E-01	1,14E-01
2,33E-01	2,36E-02
6,69E-02	1,07E-03



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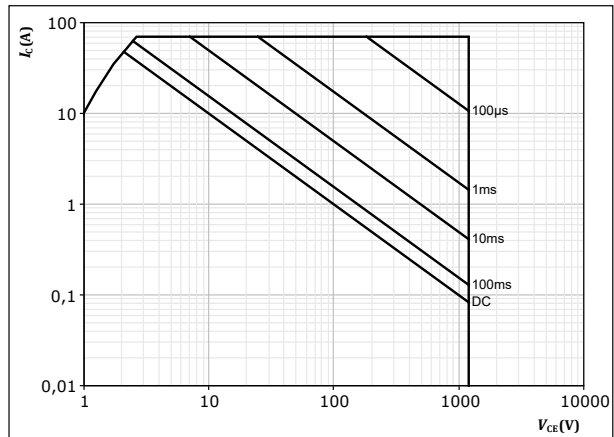
datasheet

## Inverter Switch Characteristics

figure 5. IGBT

Safe operating area

$$I_C = f(V_{CE})$$

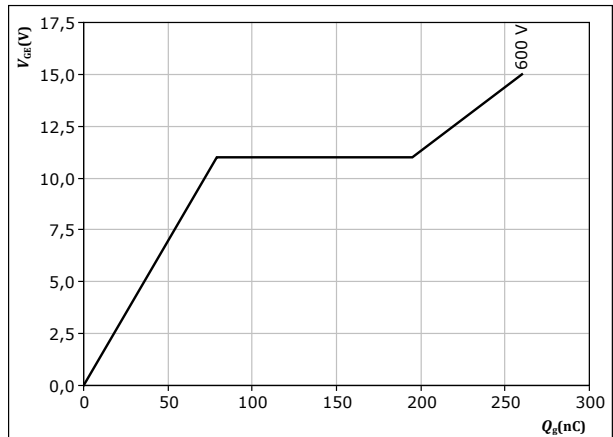


$D = \text{single pulse}$   
 $T_s = 80 \text{ } ^\circ\text{C}$   
 $V_{GE} = 15 \text{ V}$   
 $T_j = T_{jmax}$

figure 6. IGBT

Gate voltage vs gate charge

$$V_{GE} = f(Q_g)$$



$I_C = 35 \text{ A}$   
 $T_j = 25 \text{ } ^\circ\text{C}$



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## Inverter Diode Characteristics

figure 7. FWD

Typical forward characteristics

$$I_F = f(V_F)$$

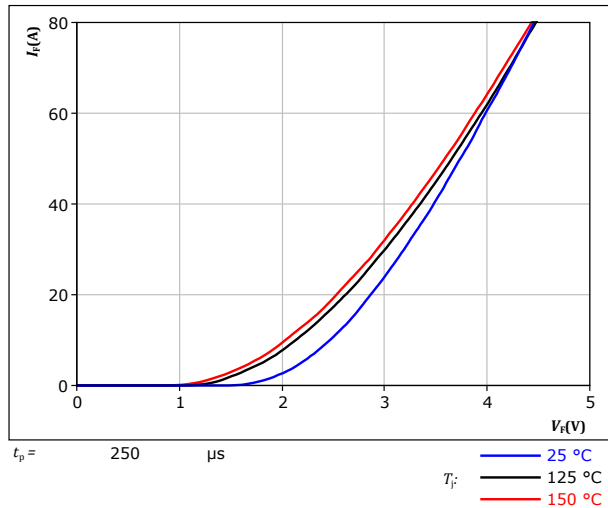
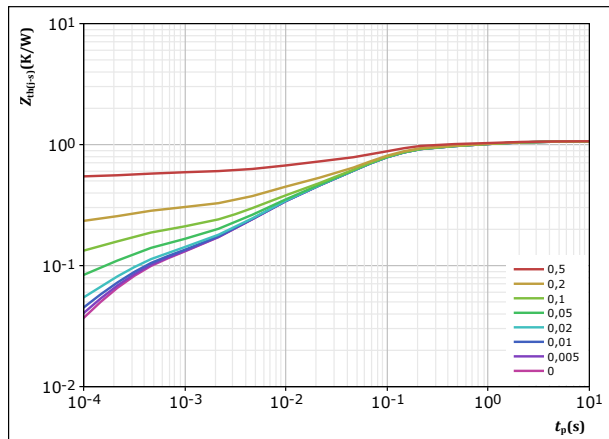


figure 8. FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D =$	$t_p / T$	
$R_{th(j-s)} =$	1,066	K/W
FWD thermal model values		
$R$ (K/W)	$\tau$ (s)	
2,57E-02	6,85E+00	
1,35E-01	7,68E-01	
6,16E-01	6,78E-02	
2,02E-01	6,16E-03	
9,26E-02	2,29E-04	



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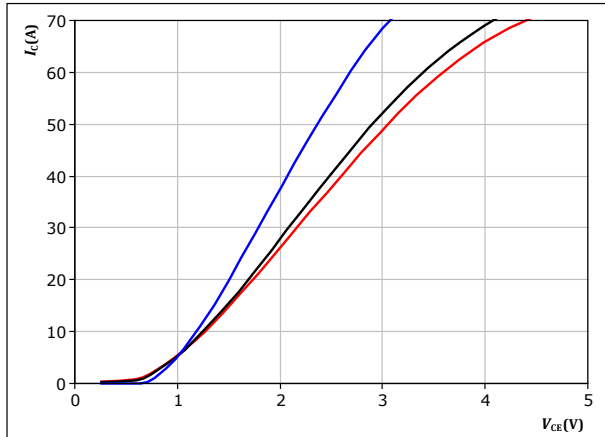
# 10-PY12PMA035M703-P589A73Y datasheet

## Brake Switch Characteristics

figure 9. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

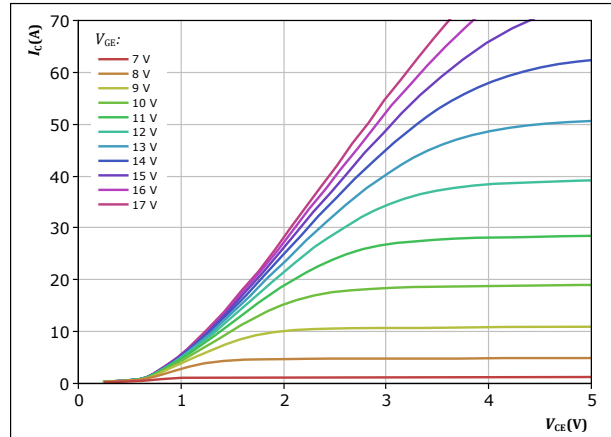


$t_p = 250 \mu s$   
 $V_{GE} = 15 V$   
 $T_j:$  25 °C, 125 °C, 150 °C

figure 10. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

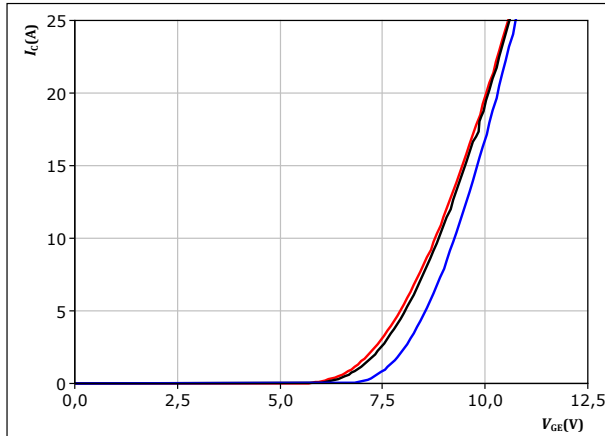


$t_p = 250 \mu s$   
 $T_j = 150 \text{ °C}$   
 $V_{GE}$  from 7 V to 17 V in steps of 1 V

figure 11. IGBT

Typical transfer characteristics

$$I_C = f(V_{GE})$$

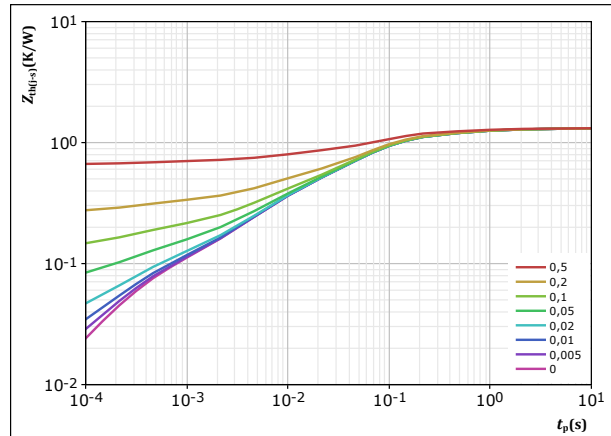


$t_p = 250 \mu s$   
 $V_{CE} = 10 V$   
 $T_j:$  25 °C, 125 °C, 150 °C

figure 12. IGBT

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T = 1,314 \text{ K/W}$   
IGBT thermal model values  

$R \text{ (K/W)}$	$\tau \text{ (s)}$
4,80E-02	4,95E+00
2,14E-01	4,62E-01
7,66E-01	6,41E-02
2,24E-01	6,11E-03
6,85E-02	3,04E-04



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datasheet

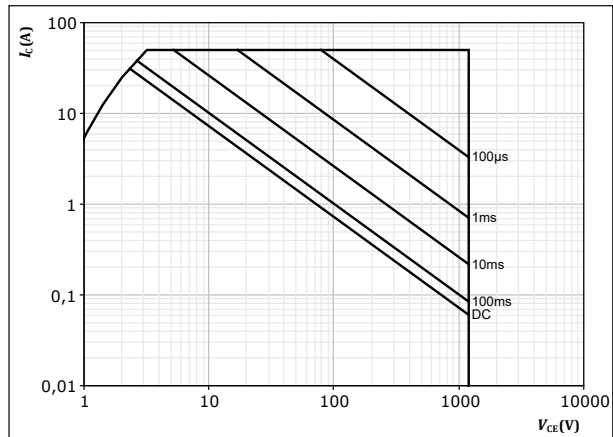
## Brake Switch Characteristics

figure 13.

IGBT

Safe operating area

$$I_C = f(V_{CE})$$



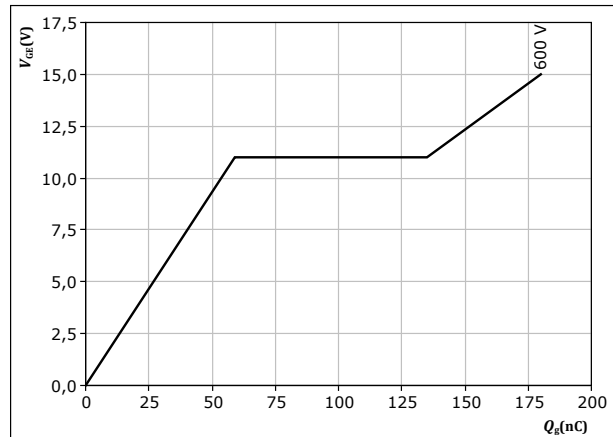
$D =$  single pulse  
 $T_s = 80$  °C  
 $V_{GE} = 15$  V  
 $T_j = T_{jmax}$

figure 14.

IGBT

Gate voltage vs gate charge

$$V_{GE} = f(Q_g)$$



$I_C = 25$  A  
 $T_j = 25$  °C



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## Brake Diode Characteristics

figure 15.

FWD

Typical forward characteristics

$$I_F = f(V_F)$$

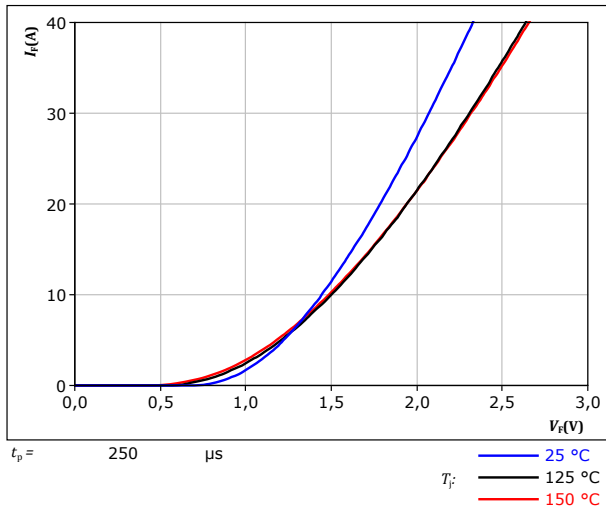
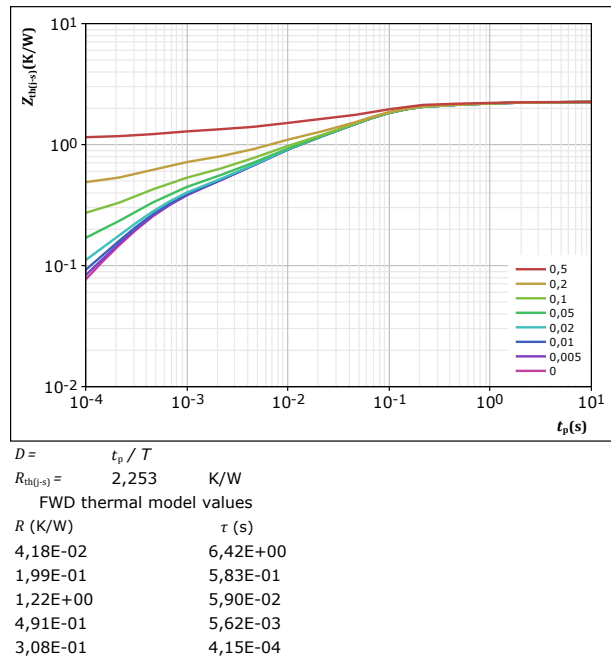


figure 16.

FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$





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## Rectifier Diode Characteristics

figure 17.

Rectifier

Typical forward characteristics

$$I_F = f(V_F)$$

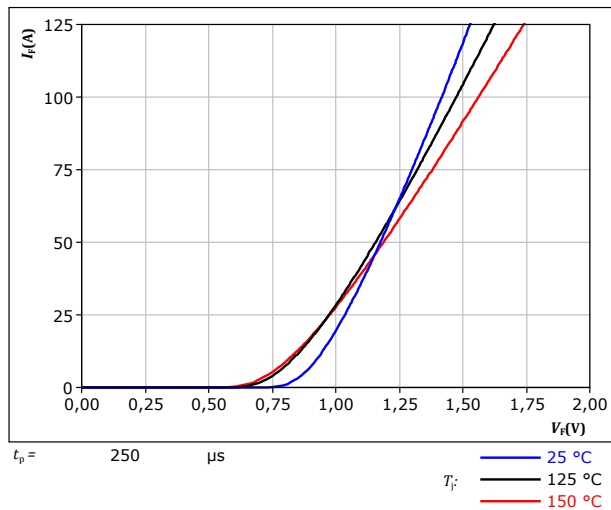
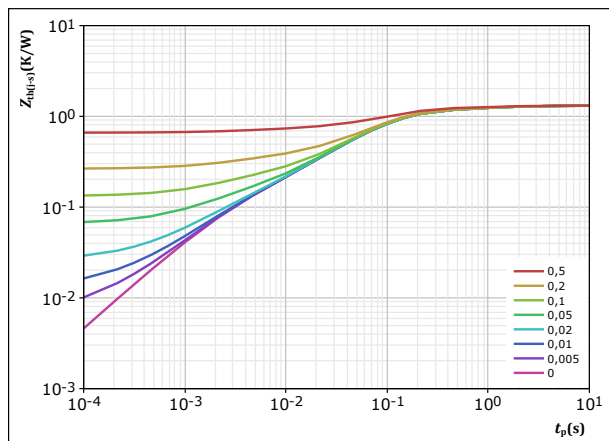


figure 18.

Rectifier

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$





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datasheet

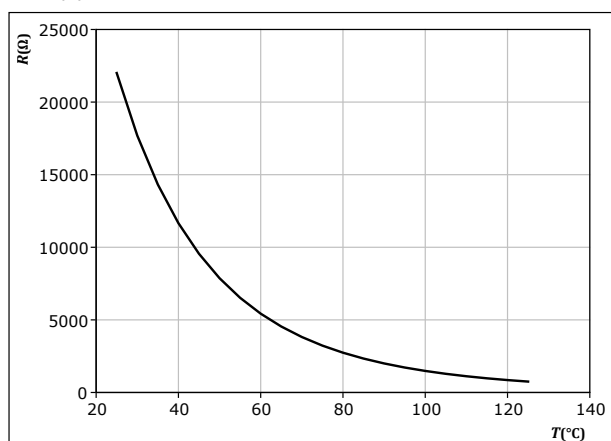
## Thermistor Characteristics

figure 19.

Thermistor

Typical NTC characteristic as function of temperature

$$R_T = f(T)$$





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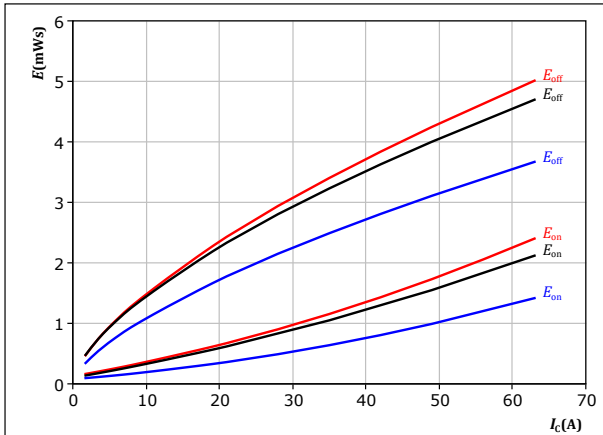
## Inverter Switching Characteristics

figure 20.

IGBT

Typical switching energy losses as a function of collector current

$$E = f(I_C)$$



With an inductive load at

$V_{CE} = 600 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $R_{gon} = 4 \text{ } \Omega$   
 $R_{goff} = 4 \text{ } \Omega$

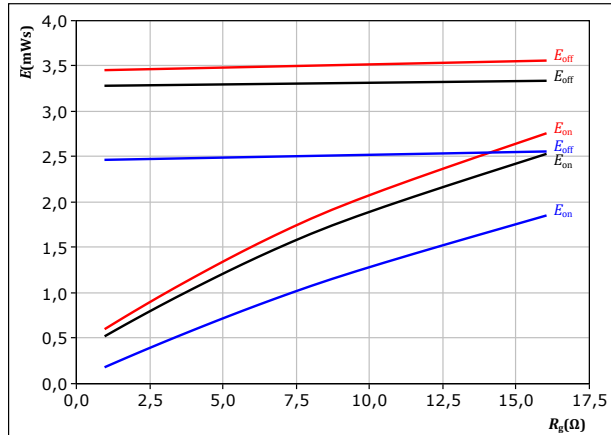
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 21.

IGBT

Typical switching energy losses as a function of IGBT turn on gate resistor

$$E = f(R_g)$$



With an inductive load at

$V_{CE} = 600 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $I_C = 35 \text{ A}$

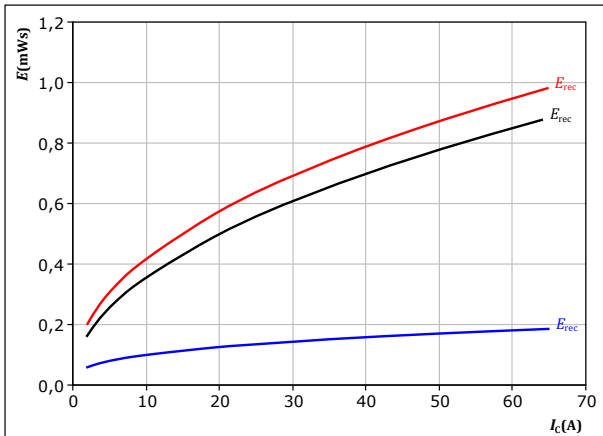
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 22.

FWD

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_C)$$



With an inductive load at

$V_{CE} = 600 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $R_{gon} = 4 \text{ } \Omega$

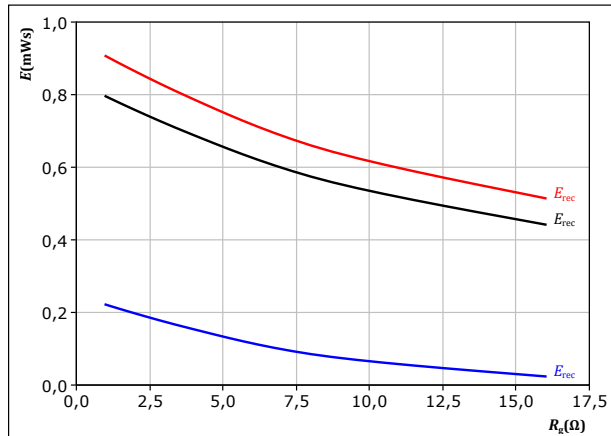
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 23.

FWD

Typical reverse recovered energy loss as a function of IGBT turn on gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$V_{CE} = 600 \text{ V}$   
 $V_{GE} = \pm 15 \text{ V}$   
 $I_C = 35 \text{ A}$

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C



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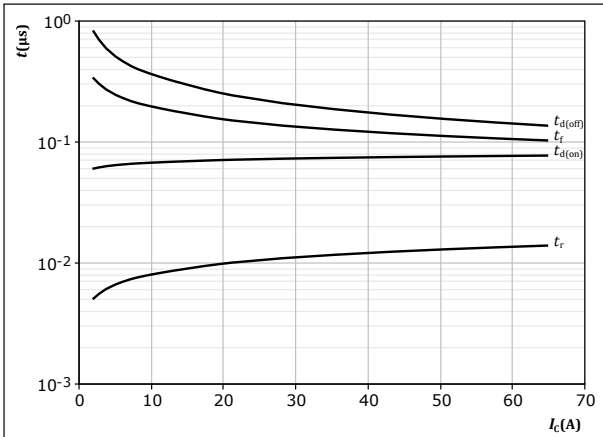
# 10-PY12PMA035M703-P589A73Y datasheet

## Inverter Switching Characteristics

figure 24.

IGBT

Typical switching times as a function of collector current  
 $t = f(I_c)$



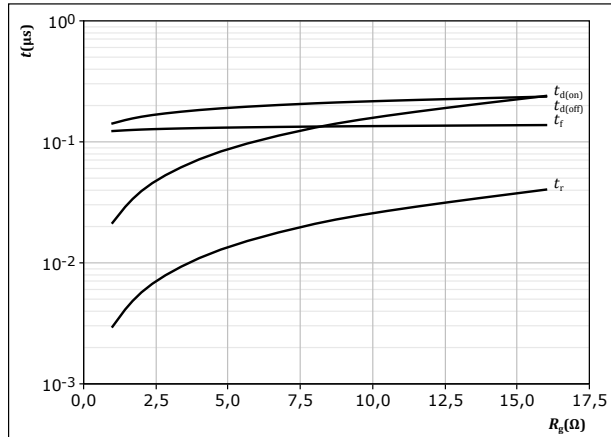
With an inductive load at

$T_j = 150$  °C  
 $V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $R_{gon} = 4$   $\Omega$   
 $R_{goff} = 4$   $\Omega$

figure 25.

IGBT

Typical switching times as a function of IGBT turn on gate resistor  
 $t = f(R_g)$



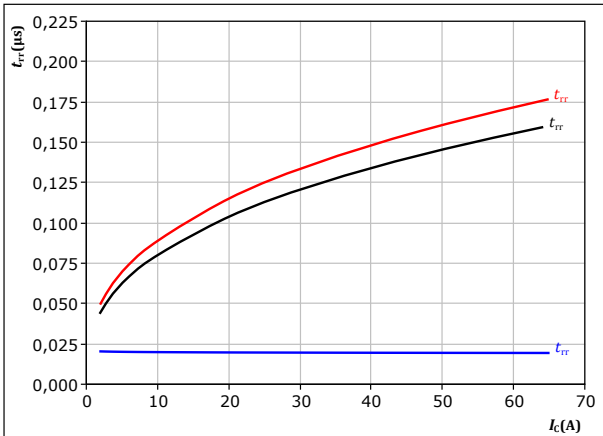
With an inductive load at

$T_j = 150$  °C  
 $V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $I_c = 35$  A

figure 26.

FWD

Typical reverse recovery time as a function of collector current  
 $t_{rr} = f(I_c)$



With an inductive load at

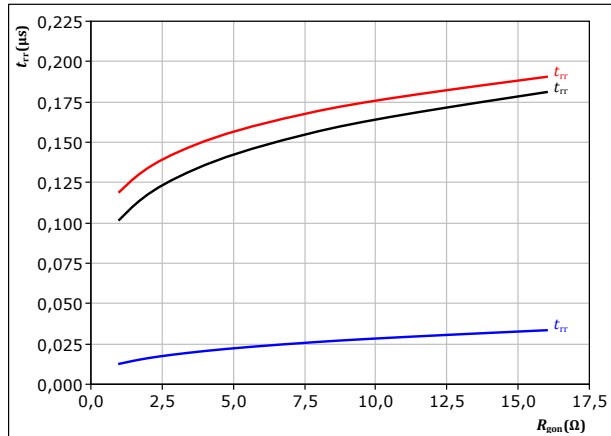
$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $R_{gon} = 4$   $\Omega$

$T_j$ : 25 °C (blue)  
125 °C (black)  
150 °C (red)

figure 27.

FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor  
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $I_c = 35$  A

$T_j$ : 25 °C (blue)  
125 °C (black)  
150 °C (red)



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# 10-PY12PMA035M703-P589A73Y datasheet

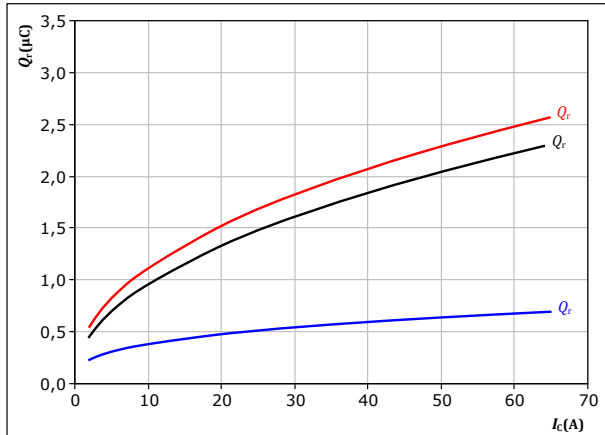
## Inverter Switching Characteristics

figure 28.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $R_{gon} = 4$  Ω

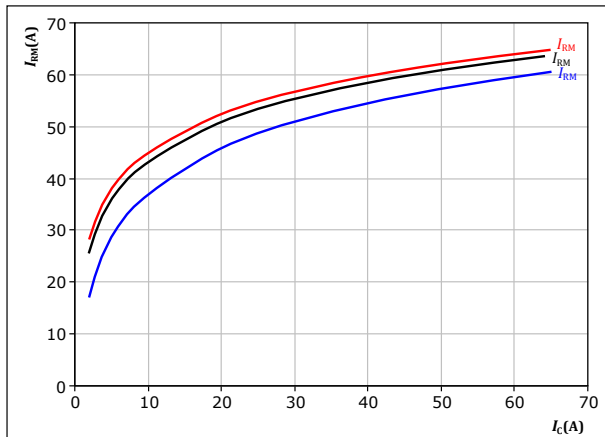
$T_j$ : 25 °C  
125 °C  
150 °C

figure 30.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $R_{gon} = 4$  Ω

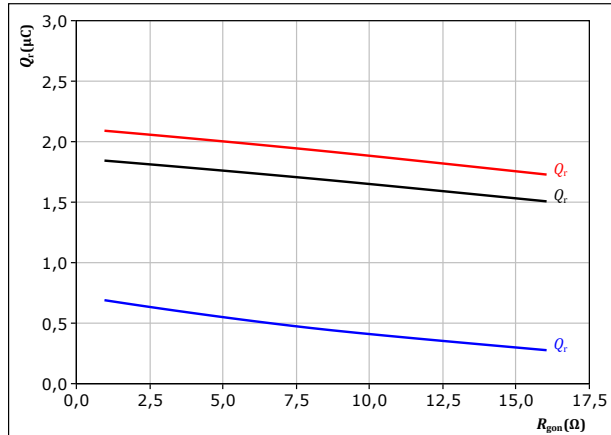
$T_j$ : 25 °C  
125 °C  
150 °C

figure 29.

FWD

Typical recovered charge as a function of IGBT turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $I_c = 35$  A

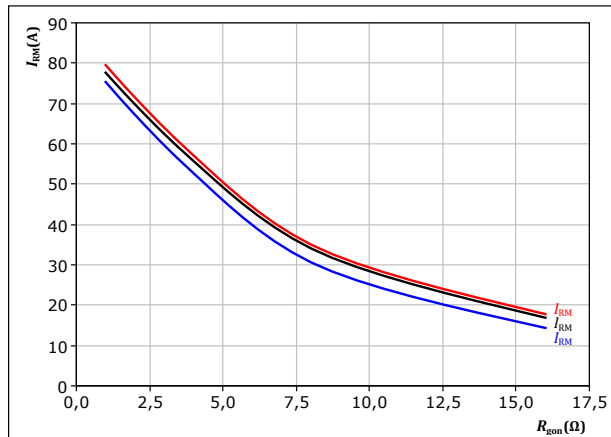
$T_j$ : 25 °C  
125 °C  
150 °C

figure 31.

FWD

Typical peak reverse recovery current as a function of IGBT turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $I_c = 35$  A

$T_j$ : 25 °C  
125 °C  
150 °C

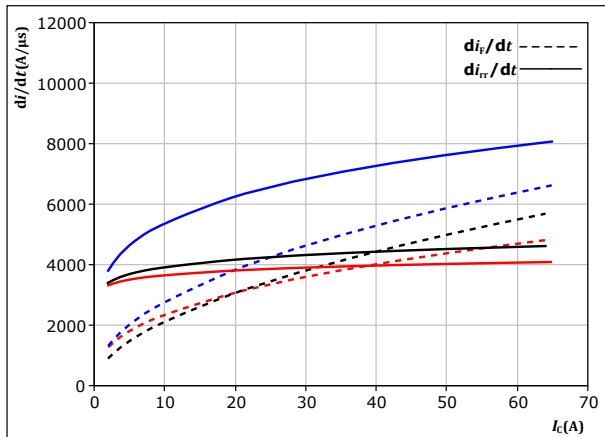


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## Inverter Switching Characteristics

figure 32. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current  
 $di_f/dt, di_r/dt = f(I_C)$

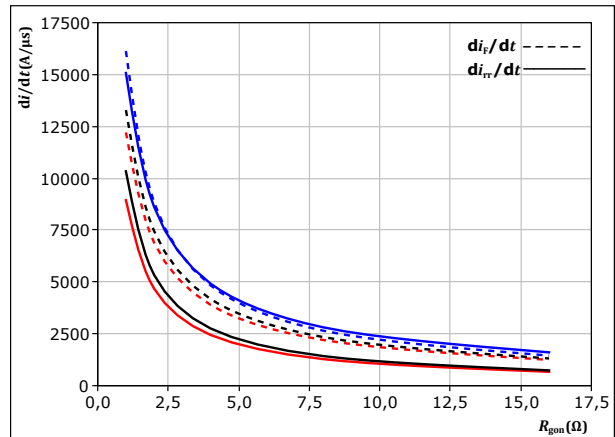


With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $R_{gon} = 4$   $\Omega$   
 $T_j: 25$  °C  
 $125$  °C  
 $150$  °C

figure 33. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor  
 $di_f/dt, di_r/dt = f(R_{gon})$



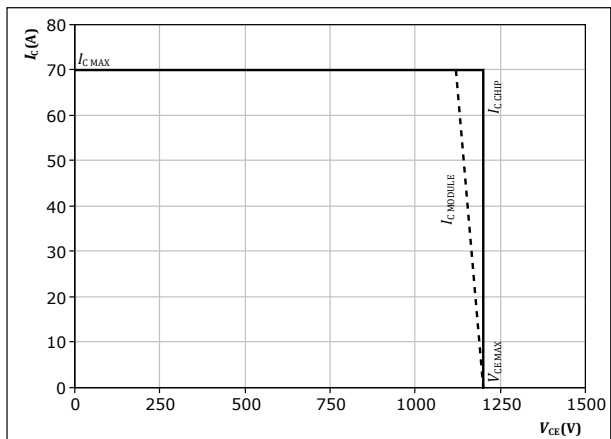
With an inductive load at

$V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $I_C = 35$  A  
 $T_j: 25$  °C  
 $125$  °C  
 $150$  °C

figure 34. IGBT

Reverse bias safe operating area

$I_C = f(V_{CE})$



At  $T_j = 150$  °C  
 $R_{gon} = 4$   $\Omega$   
 $R_{goff} = 4$   $\Omega$



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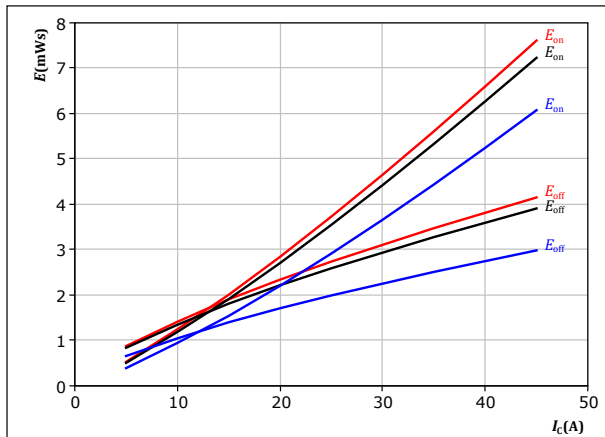
# 10-PY12PMA035M703-P589A73Y datasheet

## Brake Switching Characteristics

figure 35. IGBT

Typical switching energy losses as a function of collector current

$$E = f(I_C)$$



With an inductive load at

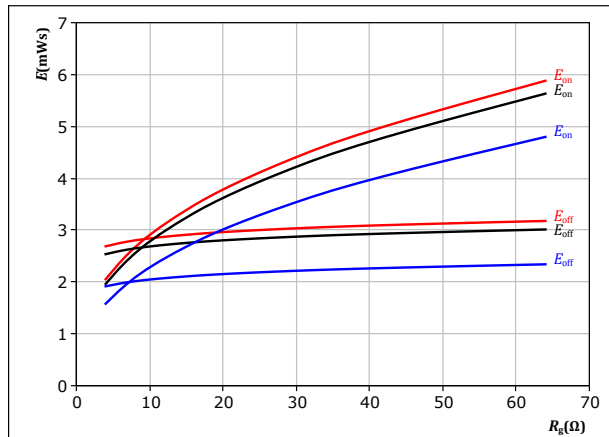
$V_{CE} = 700 \text{ V}$   
 $V_{GE} = 0/15 \text{ V}$   
 $R_{gon} = 16 \text{ } \Omega$   
 $R_{goff} = 16 \text{ } \Omega$

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 36. IGBT

Typical switching energy losses as a function of IGBT turn on gate resistor

$$E = f(R_g)$$



With an inductive load at

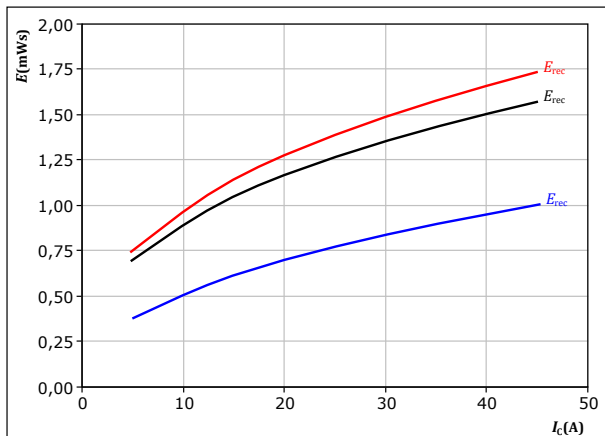
$V_{CE} = 700 \text{ V}$   
 $V_{GE} = 0/15 \text{ V}$   
 $I_C = 25 \text{ A}$

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 37. FWD

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_C)$$



With an inductive load at

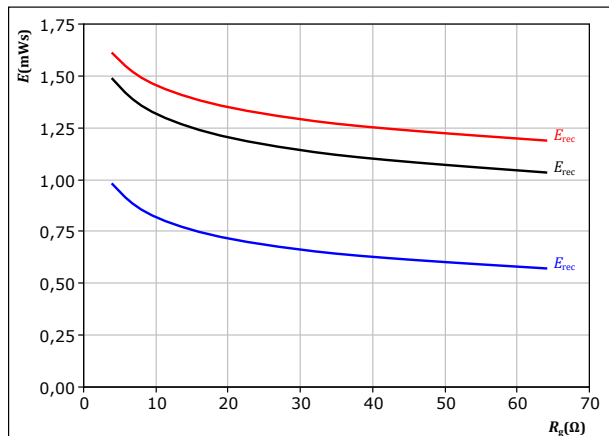
$V_{CE} = 700 \text{ V}$   
 $V_{GE} = 0/15 \text{ V}$   
 $R_{gon} = 16 \text{ } \Omega$

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 38. FWD

Typical reverse recovered energy loss as a function of IGBT turn on gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$V_{CE} = 700 \text{ V}$   
 $V_{GE} = 0/15 \text{ V}$   
 $I_C = 25 \text{ A}$

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C



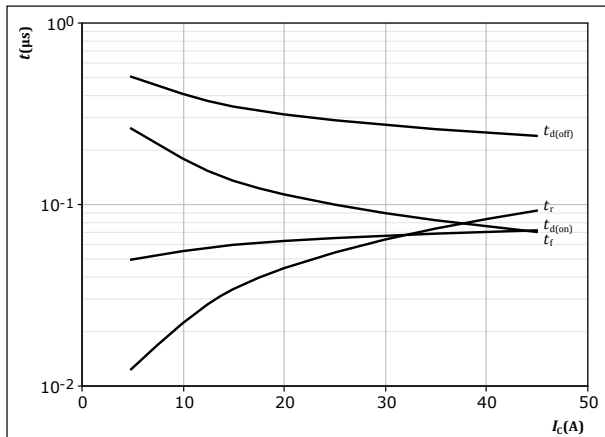
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## Brake Switching Characteristics

figure 39. IGBT

Typical switching times as a function of collector current  
 $t = f(I_c)$

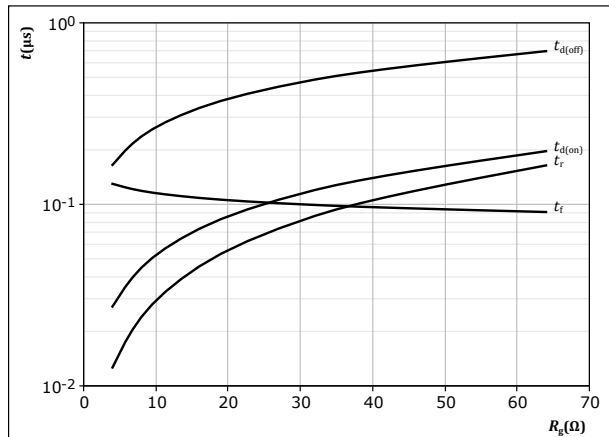


With an inductive load at

$T_j = 150$  °C  
 $V_{CE} = 700$  V  
 $V_{GE} = 0/15$  V  
 $R_{gon} = 16$  Ω  
 $R_{goff} = 16$  Ω

figure 40. IGBT

Typical switching times as a function of IGBT turn on gate resistor  
 $t = f(R_g)$

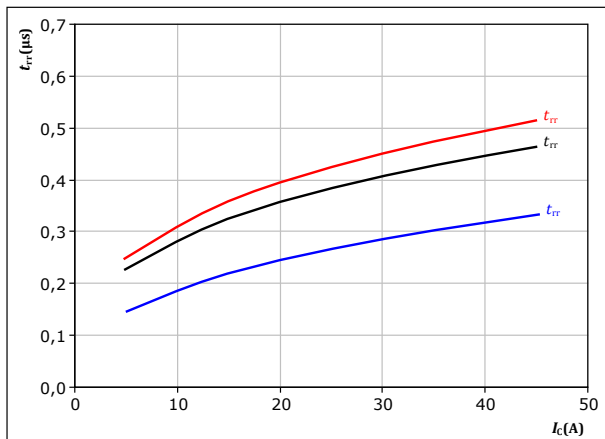


With an inductive load at

$T_j = 150$  °C  
 $V_{CE} = 700$  V  
 $V_{GE} = 0/15$  V  
 $I_c = 25$  A

figure 41. FWD

Typical reverse recovery time as a function of collector current  
 $t_{rr} = f(I_c)$



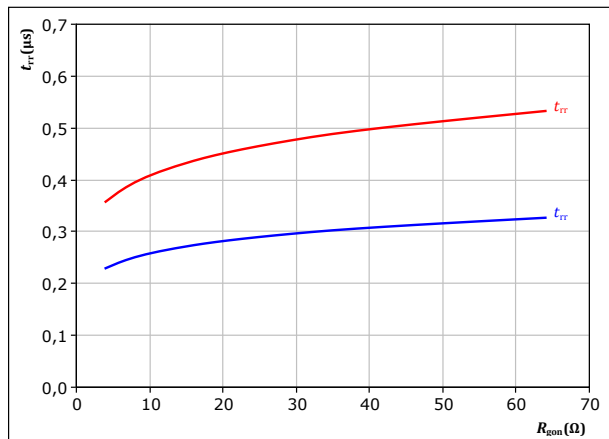
With an inductive load at

$V_{CE} = 700$  V  
 $V_{GE} = 0/15$  V  
 $R_{gon} = 16$  Ω

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 42. FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor  
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 700$  V  
 $V_{GE} = 0/15$  V  
 $I_c = 25$  A

$T_j$ :  
— 25 °C  
— 150 °C



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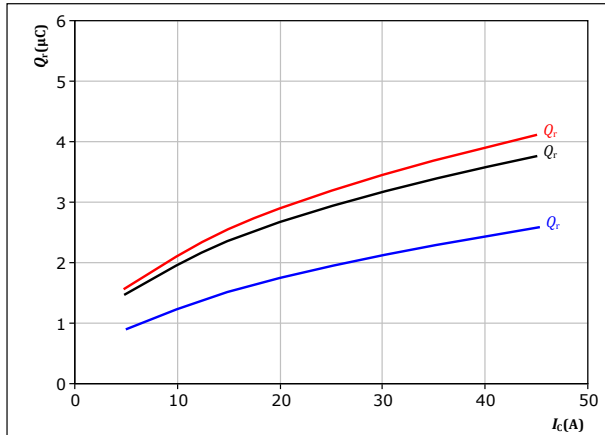
## Brake Switching Characteristics

figure 43.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

$V_{CE} = 700$  V  
 $V_{GE} = 0/15$  V  
 $R_{gon} = 16$  Ω

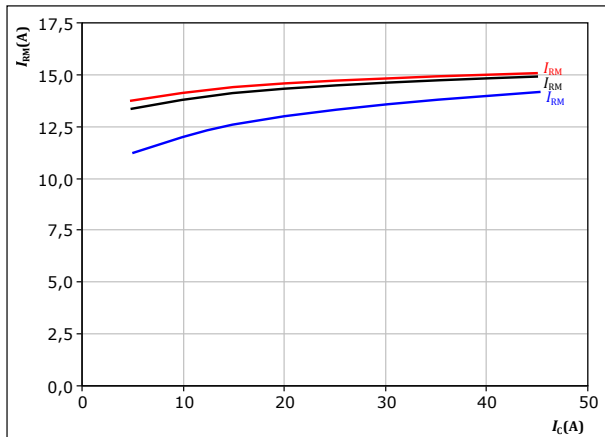
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 45.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

$V_{CE} = 700$  V  
 $V_{GE} = 0/15$  V  
 $R_{gon} = 16$  Ω

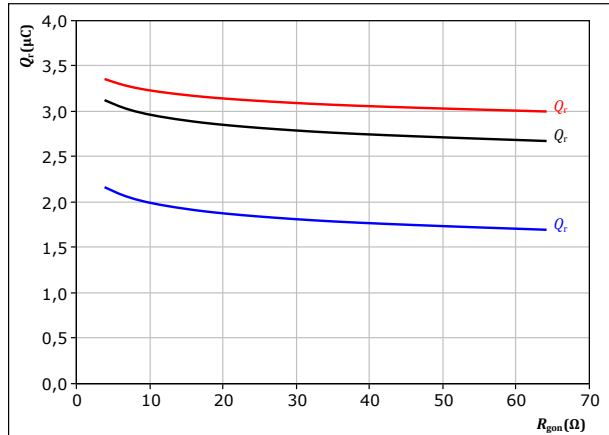
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 44.

FWD

Typical recovered charge as a function of IGBT turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

$V_{CE} = 700$  V  
 $V_{GE} = 0/15$  V  
 $I_c = 25$  A

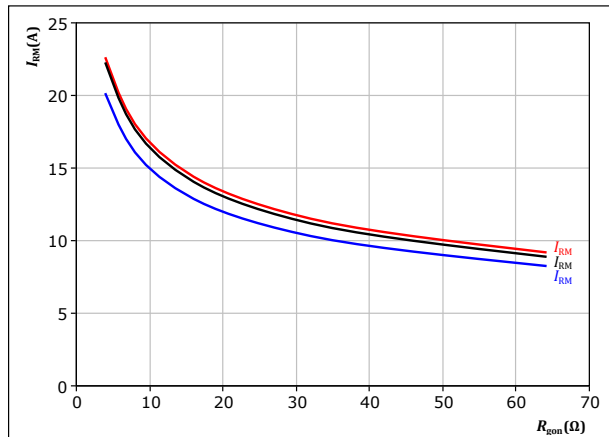
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 46.

FWD

Typical peak reverse recovery current as a function of IGBT turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$V_{CE} = 700$  V  
 $V_{GE} = 0/15$  V  
 $I_c = 25$  A

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C



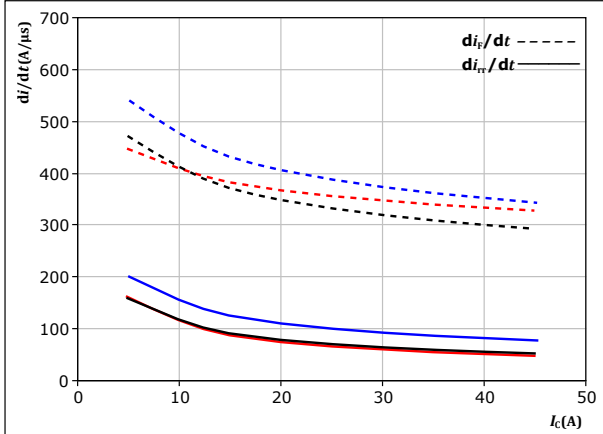
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datasheet

## Brake Switching Characteristics

figure 47. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current  
 $di_f/dt, di_r/dt = f(I_C)$



With an inductive load at

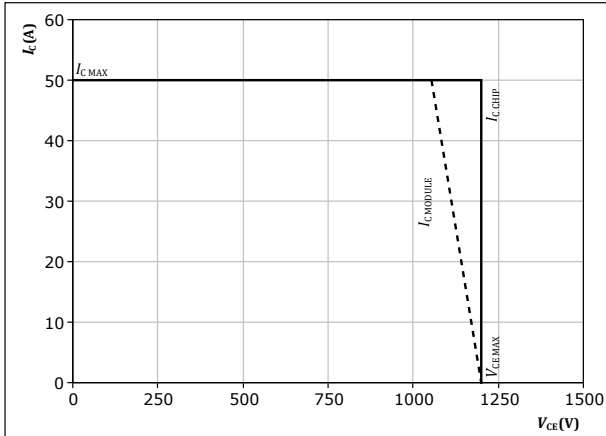
$V_{CE} = 700$  V  
 $V_{GE} = 0/15$  V  
 $R_{gon} = 16$   $\Omega$

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 49. IGBT

Reverse bias safe operating area

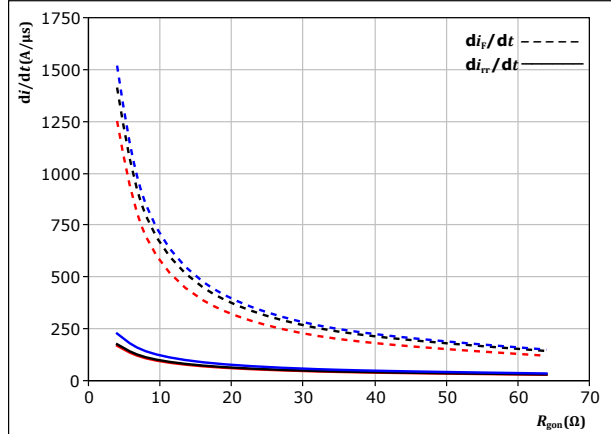
$I_C = f(V_{CE})$



At  $T_j = 150$  °C  
 $R_{gon} = 16$   $\Omega$   
 $R_{goff} = 16$   $\Omega$

figure 48. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor  
 $di_f/dt, di_r/dt = f(R_{gon})$



With an inductive load at

$V_{CE} = 700$  V  
 $V_{GE} = 0/15$  V  
 $I_C = 25$  A

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C



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# 10-PY12PMA035M703-P589A73Y

datasheet

## Switching Definitions

figure 50. IGBT  
Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$  ( $t_{Eoff}$  = integrating time for  $E_{off}$ )

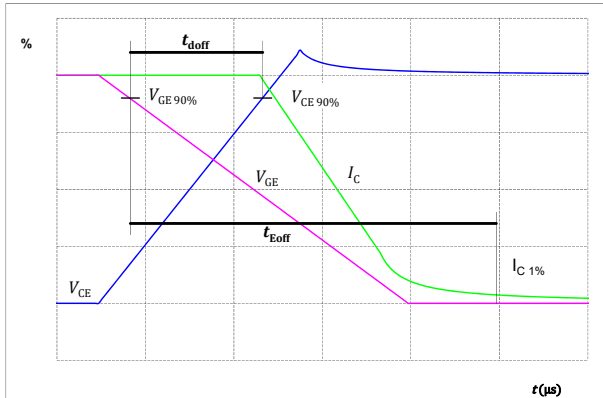


figure 51. IGBT  
Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$  ( $t_{Eon}$  = integrating time for  $E_{on}$ )

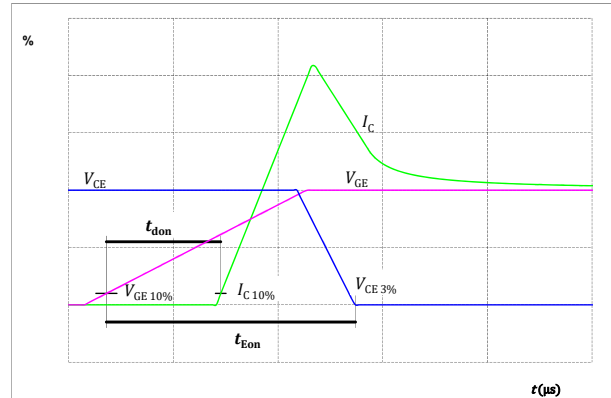


figure 52. IGBT  
Turn-off Switching Waveforms & definition of  $t_f$

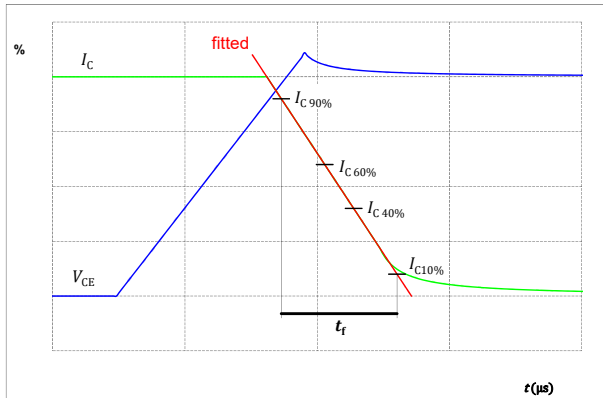
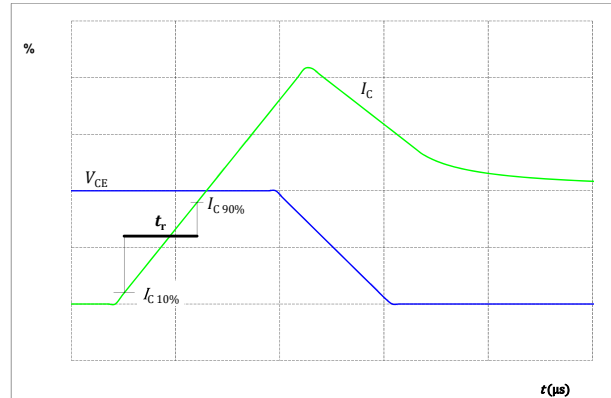


figure 53. IGBT  
Turn-on Switching Waveforms & definition of  $t_r$





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## Switching Definitions

figure 54.

FWD

Turn-off Switching Waveforms & definition of  $t_{rr}$

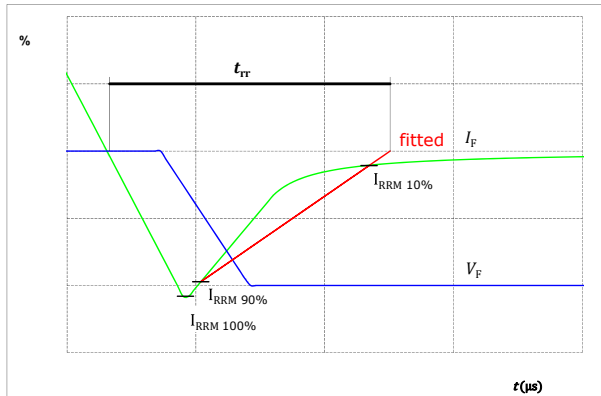
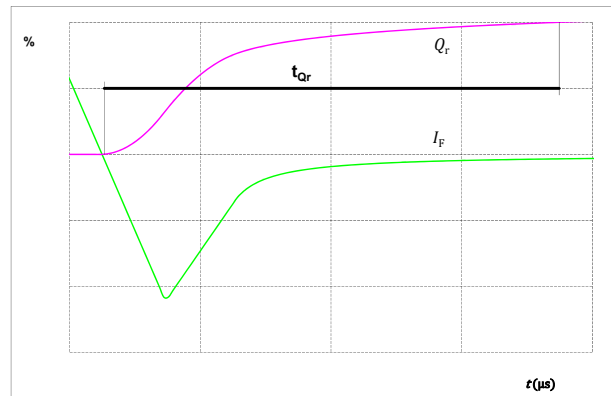


figure 55.

FWD

Turn-on Switching Waveforms & definition of  $t_{Qr}$  ( $t_{Qr}$  = integrating time for  $Q_r$ )





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# 10-PY12PMA035M703-P589A73Y

datasheet

Ordering Code	
Version	Ordering Code
Without thermal paste	10-PY12PMA035M703-P589A73Y
With thermal paste (5,2 W/mK, PTM6000HV)	10-PY12PMA035M703-P589A73Y-/7/

Marking					
	Text	Name NN-NNNNNNNNNNNNNNNN- TTTTIVV	Date code WWYY	UL & VIN UL VIN	Lot LLLL
	Datamatrix	Type&Ver TTTTTTVV	Lot number LLLLL	Serial SSSS	Date code WWYY

Outline																																																																																																																																							
<p>Pin table [mm]</p> <table><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>52,55</td><td>0</td><td>G27</td></tr><tr><td>2</td><td>47,7</td><td>0</td><td>DC-Rect</td></tr><tr><td>3</td><td>44,8</td><td>0</td><td>DC-Rect</td></tr><tr><td>4</td><td>37,8</td><td>0</td><td>DC+Rect</td></tr><tr><td>5</td><td>37,8</td><td>2,8</td><td>DC+Rect</td></tr><tr><td>6</td><td>35</td><td>0</td><td>DC+Inv</td></tr><tr><td>7</td><td>35</td><td>2,8</td><td>DC+Inv</td></tr><tr><td>8</td><td>28</td><td>0</td><td>Therm1</td></tr><tr><td>9</td><td>25,2</td><td>0</td><td>Therm2</td></tr><tr><td>10</td><td>22,4</td><td>0</td><td>DC-3</td></tr><tr><td>11</td><td>19,6</td><td>0</td><td>G15</td></tr><tr><td>12</td><td>16,8</td><td>0</td><td>S15</td></tr><tr><td>13</td><td>14</td><td>0</td><td>DC-2</td></tr><tr><td>14</td><td>11,2</td><td>0</td><td>G13</td></tr><tr><td>15</td><td>8,4</td><td>0</td><td>S13</td></tr><tr><td>16</td><td>5,6</td><td>0</td><td>DC-1</td></tr><tr><td>17</td><td>2,8</td><td>0</td><td>G11</td></tr><tr><td>18</td><td>0</td><td>0</td><td>S11</td></tr><tr><td>19</td><td>0</td><td>28,5</td><td>Ph1</td></tr><tr><td>20</td><td>2,8</td><td>28,5</td><td>G12</td></tr><tr><td>21</td><td>7,5</td><td>28,5</td><td>S12</td></tr><tr><td>22</td><td>14,5</td><td>28,5</td><td>Ph2</td></tr><tr><td>23</td><td>17,3</td><td>28,5</td><td>G14</td></tr><tr><td>24</td><td>22</td><td>28,5</td><td>S14</td></tr><tr><td>25</td><td>29</td><td>28,5</td><td>Ph3</td></tr><tr><td>26</td><td>31,8</td><td>28,5</td><td>G16</td></tr><tr><td>27</td><td>36,5</td><td>28,5</td><td>S16</td></tr><tr><td>28</td><td>43,5</td><td>28,5</td><td>ACIn1</td></tr><tr><td>29</td><td>52,55</td><td>25</td><td>ACIn2</td></tr><tr><td>30</td><td>52,55</td><td>16,9</td><td>ACIn3</td></tr><tr><td>31</td><td>52,55</td><td>8,6</td><td>Br</td></tr><tr><td>32</td><td>52,55</td><td>2,8</td><td>DC-Br</td></tr></tbody></table>				Pin	X	Y	Function	1	52,55	0	G27	2	47,7	0	DC-Rect	3	44,8	0	DC-Rect	4	37,8	0	DC+Rect	5	37,8	2,8	DC+Rect	6	35	0	DC+Inv	7	35	2,8	DC+Inv	8	28	0	Therm1	9	25,2	0	Therm2	10	22,4	0	DC-3	11	19,6	0	G15	12	16,8	0	S15	13	14	0	DC-2	14	11,2	0	G13	15	8,4	0	S13	16	5,6	0	DC-1	17	2,8	0	G11	18	0	0	S11	19	0	28,5	Ph1	20	2,8	28,5	G12	21	7,5	28,5	S12	22	14,5	28,5	Ph2	23	17,3	28,5	G14	24	22	28,5	S14	25	29	28,5	Ph3	26	31,8	28,5	G16	27	36,5	28,5	S16	28	43,5	28,5	ACIn1	29	52,55	25	ACIn2	30	52,55	16,9	ACIn3	31	52,55	8,6	Br	32	52,55	2,8	DC-Br
Pin	X	Y	Function																																																																																																																																				
1	52,55	0	G27																																																																																																																																				
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3	44,8	0	DC-Rect																																																																																																																																				
4	37,8	0	DC+Rect																																																																																																																																				
5	37,8	2,8	DC+Rect																																																																																																																																				
6	35	0	DC+Inv																																																																																																																																				
7	35	2,8	DC+Inv																																																																																																																																				
8	28	0	Therm1																																																																																																																																				
9	25,2	0	Therm2																																																																																																																																				
10	22,4	0	DC-3																																																																																																																																				
11	19,6	0	G15																																																																																																																																				
12	16,8	0	S15																																																																																																																																				
13	14	0	DC-2																																																																																																																																				
14	11,2	0	G13																																																																																																																																				
15	8,4	0	S13																																																																																																																																				
16	5,6	0	DC-1																																																																																																																																				
17	2,8	0	G11																																																																																																																																				
18	0	0	S11																																																																																																																																				
19	0	28,5	Ph1																																																																																																																																				
20	2,8	28,5	G12																																																																																																																																				
21	7,5	28,5	S12																																																																																																																																				
22	14,5	28,5	Ph2																																																																																																																																				
23	17,3	28,5	G14																																																																																																																																				
24	22	28,5	S14																																																																																																																																				
25	29	28,5	Ph3																																																																																																																																				
26	31,8	28,5	G16																																																																																																																																				
27	36,5	28,5	S16																																																																																																																																				
28	43,5	28,5	ACIn1																																																																																																																																				
29	52,55	25	ACIn2																																																																																																																																				
30	52,55	16,9	ACIn3																																																																																																																																				
31	52,55	8,6	Br																																																																																																																																				
32	52,55	2,8	DC-Br																																																																																																																																				

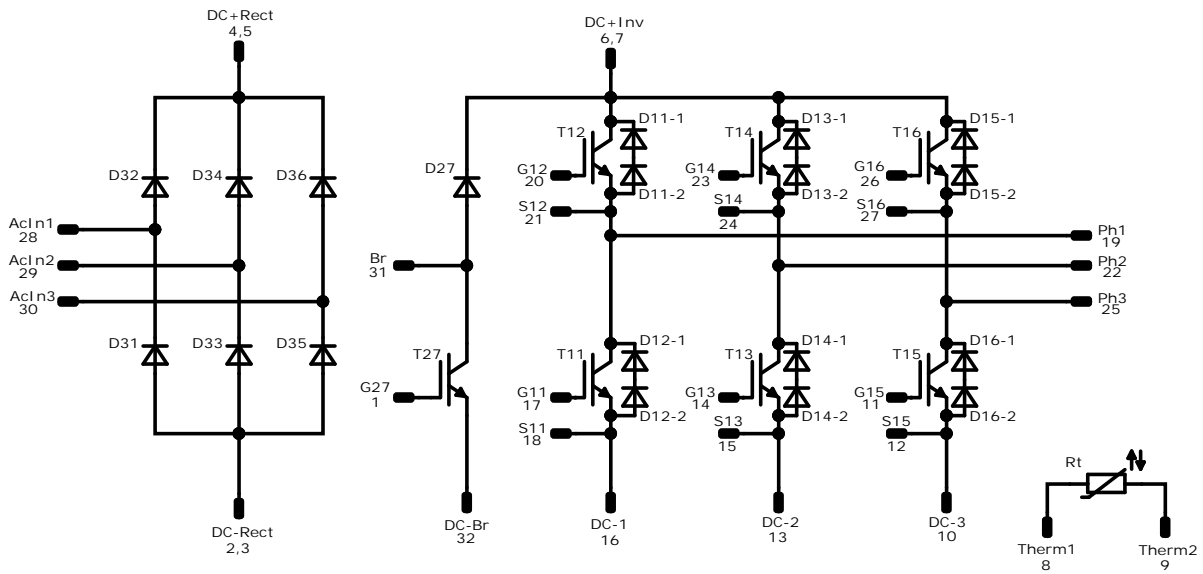


Vincotech

# 10-PY12PMA035M703-P589A73Y

datasheet

## Pinout




## Identification

ID	Component	Voltage	Current	Function	Comment
T11, T12, T13, T14, T15, T16	IGBT	1200 V	35 A	Inverter Switch	
D11-1, D11-2, D12-1, D12-2, D13-1, D13-2, D14-1, D14-2, D15-1, D15-2, D16-1, D16-2	FWD	1300 V	30 A	Inverter Diode	
T27	IGBT	1200 V	25 A	Brake Switch	
D27	FWD	1200 V	15 A	Brake Diode	
D31, D32, D33, D34, D35, D36	Rectifier	1600 V	45 A	Rectifier Diode	
Rt	Thermistor			Thermistor	



Vincotech

**10-PY12PMA035M703-P589A73Y**  
datasheet

Packaging instruction				
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ	Sample
Handling instruction				
Handling instructions for <i>flow</i> 1 packages see vincotech.com website.				
Package data				
Package data for <i>flow</i> 1 packages see vincotech.com website.				
Vincotech thermistor reference				
See Vincotech thermistor reference table at vincotech.com website.				
UL recognition and file number				
This device is UL 1557 recognized under E192116 up to a junction temperature under switching condition $T_{j,sp}=175^{\circ}\text{C}$ and up to 3500VAC/1min isolation voltage. For more information see vincotech.com website.				

Document No.:	Date:	Modification:	Pages
10-PY12PMA035M703-P589A73Y-D1-14	5 Mar. 2026	Initial Release	

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.